

74LVC4245A

Octal dual supply translating transceiver; 3-state

Rev. 13 — 27 August 2021

Product data sheet

1. General description

The 74LVC4245A is an octal dual supply translating transceiver featuring 3-state bus compatible outputs in both send and receive directions. It is designed to interface between a 3 V and 5 V bus in a mixed 3 V and 5 V supply environment. The device features an output enable input (\overline{OE}) and a send/receive input (DIR) for direction control. A HIGH on \overline{OE} causes the outputs to assume a high-impedance OFF-state, effectively isolating the buses. In suspend mode, when either supply is zero, there is no current path between supplies. $V_{CCA} \geq V_{CCB}$, except in suspend mode. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

2. Features and benefits

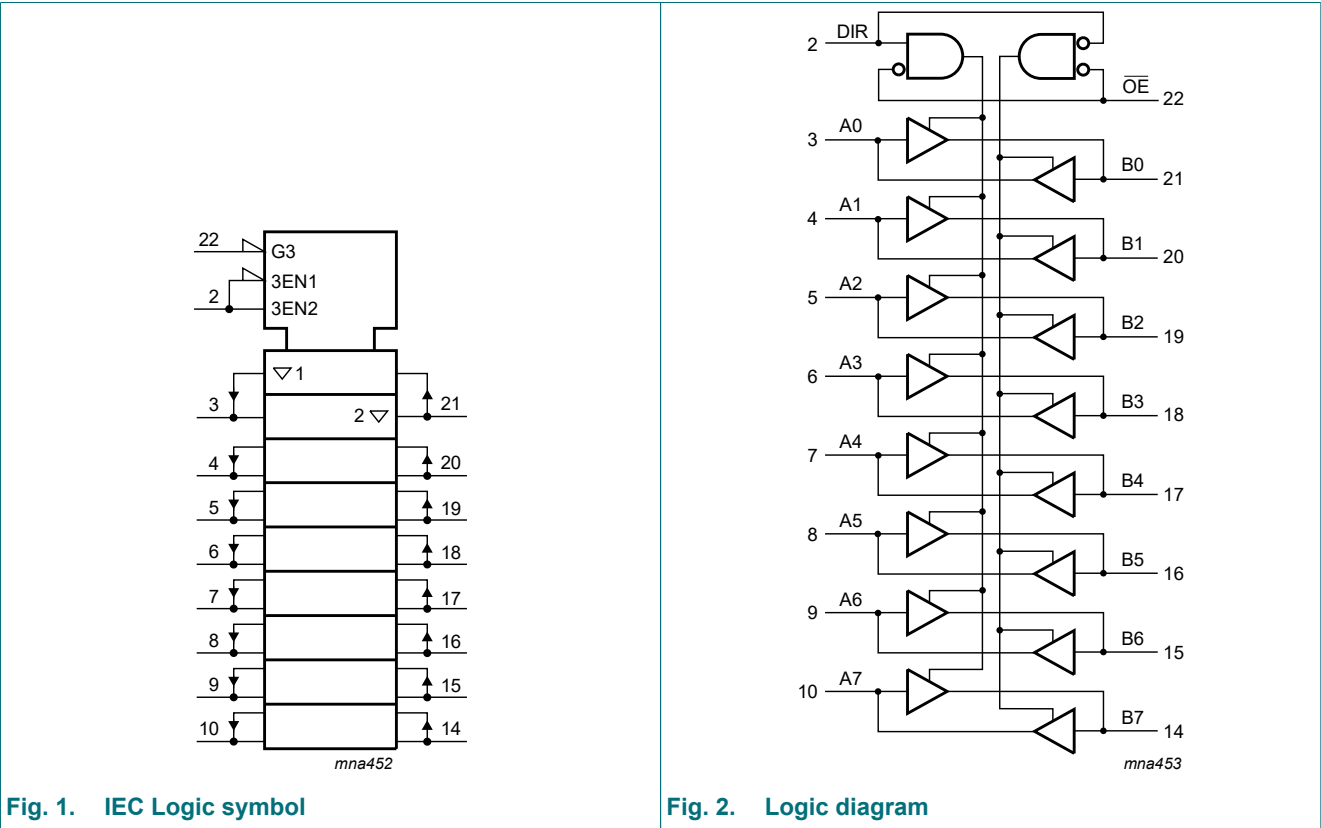
- 5 V tolerant inputs/outputs, for interfacing with 5 V logic
- Wide supply voltage range:
 - 3 V bus ($V_{CC(B)}$): 1.5 V to 3.6 V
 - 5 V bus ($V_{CC(A)}$): 1.5 V to 5.5 V
- CMOS low-power consumption
- TTL interface capability at 3.3 V
- Overvoltage tolerant control inputs to 5.5 V
- High-impedance when $V_{CC(A)} = 0$ V
- Complies with JEDEC standard no. JESD8B/JESD36
- Latch-up performance meets requirements of JESD78 Class 1
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

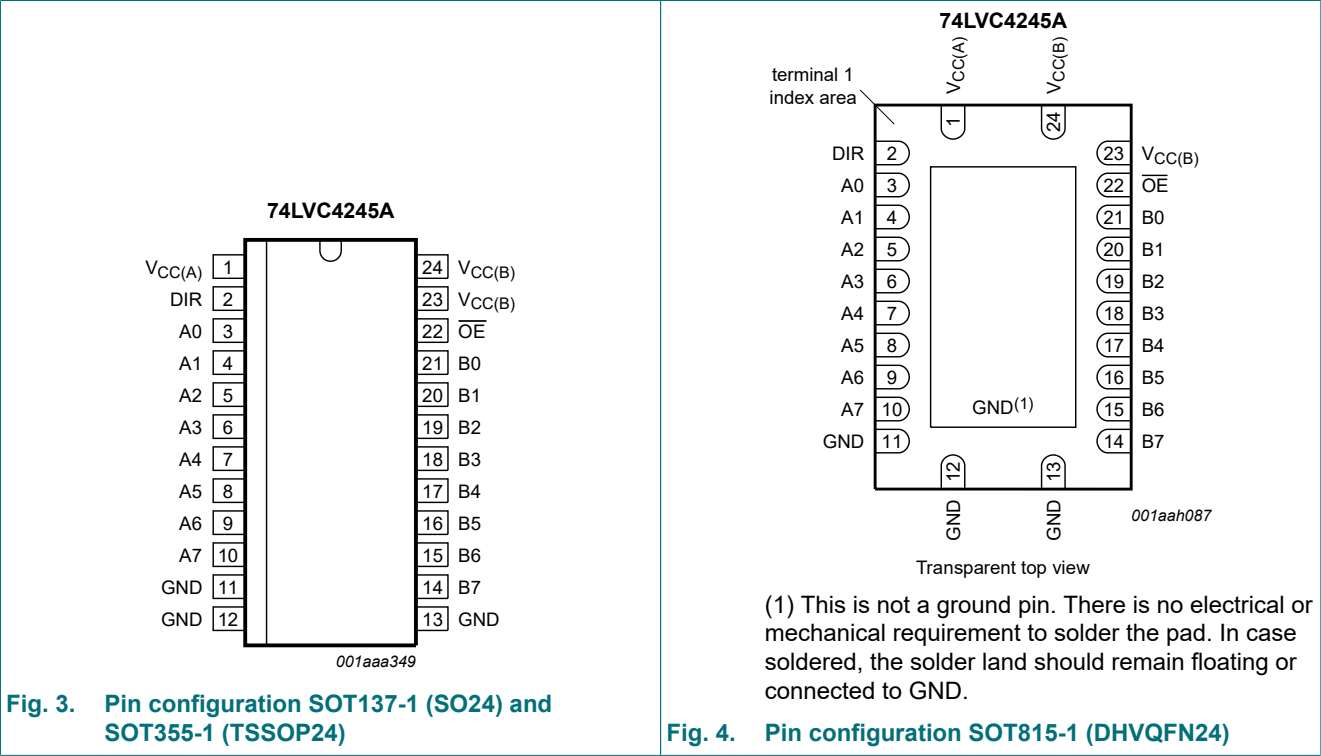
Type number	Package			
	Temperature range	Name	Description	Version
74LVC4245AD	-40 °C to +125 °C	SO24	plastic small outline package; 24 leads; body width 7.5 mm	SOT137-1
74LVC4245APW	-40 °C to +125 °C	TSSOP24	plastic thin shrink small outline package; 24 leads; body width 4.4 mm	SOT355-1
74LVC4245ABQ	-40 °C to +125 °C	DHVQFN24	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 24 terminals; body 3.5 × 5.5 × 0.85 mm	SOT815-1

4. Functional diagram



5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
V _{CC} (A)	1	supply voltage (5 V bus)
V _{CC} (B)	23, 24	supply voltage (3 V bus)
GND	11, 12, 13	ground (0 V)
DIR	2	direction control
A0, A1, A2, A3, A4, A5, A6, A7	3, 4, 5, 6, 7, 8, 9, 10	data input or output
B0, B1, B2, B3, B4, B5, B6, B7	21, 20, 19, 18, 17, 16, 15, 14	data input or output
OE	22	output enable input (active LOW)

6. Functional description

Table 3. Functional table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

Input		Input/output	
OE	DIR	An	Bn
L	L	A = B	input
L	H	input	B = A
H	X	Z	Z

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		-0.5	+6.5	V
$V_{CC(B)}$	supply voltage B		-0.5	+4.6	V
I_{IK}	input clamping current	$V_I < 0$ V	-50	-	mA
V_I	input voltage		-0.5	+6.5	V
I_{OK}	output clamping current	$V_O > V_{CCO}$ or $V_O < 0$ V	-	± 50	mA
V_O	output voltage	output HIGH or LOW state	-0.5	$V_{CC} + 0.5$	V
		output 3-state	-0.5	+6.5	V
I_O	output current	$V_O = 0$ V to V_{CCO}	-	± 50	mA
I_{CC}	supply current		-	100	mA
I_{GND}	ground current		-100	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to +125 °C	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] V_{CCO} is the supply voltage associated with the output.

[3] For SOT137-1 (SO24) package: P_{tot} derates linearly with 16.2 mW/K above 119 °C.

For SOT355-1 (TSSOP24) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.

For SOT815-1 (DHVQFN24) package: P_{tot} derates linearly with 15.0 mW/K above 117 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{CC(A)}$	supply voltage A	$V_{CC(A)} \geq V_{CC(B)}$; see Fig. 5 for maximum speed performance	1.5	-	5.5	V
$V_{CC(B)}$	supply voltage B	$V_{CC(A)} \geq V_{CC(B)}$; see Fig. 5 for low-voltage applications	1.5	-	3.6	V
V_I	input voltage	for control inputs	0	-	5.5	V
V_O	output voltage	output HIGH or LOW state	0	-	V_{CC}	V
		output 3-state	0	-	5.5	V
T_{amb}	ambient temperature		-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC(B)} = 2.7$ V to 3.0 V	-	-	20	ns/V
		$V_{CC(B)} = 3.0$ V to 3.6 V	-	-	10	ns/V
		$V_{CC(A)} = 3.0$ V to 4.5 V	-	-	20	ns/V
		$V_{CC(A)} = 4.5$ V to 5.5 V	-	-	10	ns/V

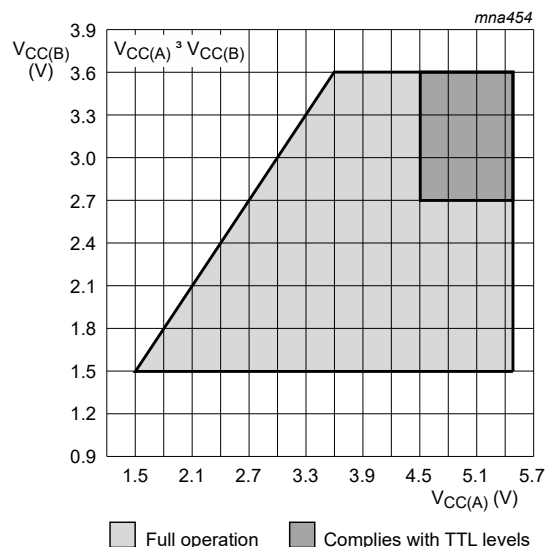


Fig. 5. Supply operation area

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
T_{amb} = -40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC(B)} = 2.7 V to 3.6 V	2.0	-	-	V
		V _{CC(A)} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC(B)} = 2.7 V to 3.6 V	-	-	0.8	V
		V _{CC(A)} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		V _{CC(B)} = 2.7 V to 3.6 V; I _O = -100 µA	V _{CC(B)} - 0.2	V _{CC(B)}	-	V
		V _{CC(B)} = 2.7 V; I _O = -12 mA	V _{CC(B)} - 0.5	-	-	V
		V _{CC(B)} = 3.0 V; I _O = -24 mA	V _{CC(B)} - 0.8	-	-	V
		V _{CC(A)} = 4.5 V to 5.5 V; I _O = -100 µA	V _{CC(A)} - 0.2	V _{CC(A)}	-	V
		V _{CC(A)} = 4.5 V; I _O = -12 mA	V _{CC(A)} - 0.5	-	-	V
		V _{CC(A)} = 4.5 V; I _O = -24 mA	V _{CC(A)} - 0.8	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		V _{CC(B)} = 2.7 V to 3.6 V; I _O = 100 µA	-	-	0.20	V
		V _{CC(B)} = 2.7 V; I _O = 12 mA	-	-	0.40	V
		V _{CC(B)} = 3.0 V; I _O = 24 mA	-	-	0.55	V
		V _{CC(A)} = 4.5 V to 5.5 V; I _O = 100 µA	-	-	0.20	V
		V _{CC(A)} = 4.5 V; I _O = 12 mA	-	-	0.40	V
		V _{CC(A)} = 4.5 V; I _O = 24 mA	-	-	0.55	V
I _I	input leakage current	V _I = 5.5 V or GND	-	±0.1	±5	µA
I _{OZ}	OFF-state output current	V _I = V _{IH} or V _{IL} [2]				
		V _{CC(B)} = 3.6 V; V _O = V _{CC(B)} or GND	-	±0.1	±5	µA
		V _{CC(A)} = 5.5 V; V _O = V _{CC(A)} or GND	-	±0.1	±5	µA

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Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
I_{CC}	supply current	$I_O = 0$ A				
		$V_{CC(B)} = 3.6$ V; other inputs at $V_{CC(B)}$ or GND	-	0.1	10	μ A
		$V_{CC(A)} = 5.5$ V; other inputs at $V_{CC(A)}$ or GND	-	0.1	10	μ A
ΔI_{CC}	additional supply current	per pin; $I_O = 0$ A				
		$V_{CC(B)} = 2.7$ V to 3.6 V; $V_I = V_{CC(B)} - 0.6$ V; other inputs at $V_{CC(B)}$ or GND	-	5	500	μ A
		$V_{CC(A)} = 4.5$ V to 5.5 V; $V_I = V_{CC(A)} - 0.6$ V; other inputs at $V_{CC(A)}$ or GND	-	5	500	μ A
C_I	input capacitance		-	4.0	-	pF
$C_{I/O}$	input/output capacitance	An and Bn	-	5.0	-	pF
$T_{amb} = -40$ °C to $+125$ °C						
V_{IH}	HIGH-level input voltage	$V_{CC(B)} = 2.7$ V to 3.6 V	2.0	-	-	V
		$V_{CC(A)} = 4.5$ V to 5.5 V	2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC(B)} = 2.7$ V to 3.6 V	-	-	0.8	V
		$V_{CC(A)} = 4.5$ V to 5.5 V	-	-	0.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$V_{CC(B)} = 2.7$ V to 3.6 V; $I_O = -100$ μ A	$V_{CC(B)} - 0.3$	-	-	V
		$V_{CC(B)} = 2.7$ V; $I_O = -12$ mA	$V_{CC(B)} - 0.65$	-	-	V
		$V_{CC(B)} = 3.0$ V; $I_O = -24$ mA	$V_{CC(B)} - 1.0$	-	-	V
		$V_{CC(A)} = 4.5$ V to 5.5 V; $I_O = -100$ μ A	$V_{CC(A)} - 0.3$	-	-	V
		$V_{CC(A)} = 4.5$ V; $I_O = -12$ mA	$V_{CC(A)} - 0.65$	-	-	V
		$V_{CC(A)} = 4.5$ V; $I_O = -24$ mA	$V_{CC(A)} - 1.0$	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$V_{CC(B)} = 2.7$ V to 3.6 V; $I_O = 100$ μ A	-	-	0.30	V
		$V_{CC(B)} = 2.7$ V; $I_O = 12$ mA	-	-	0.60	V
		$V_{CC(B)} = 3.0$ V; $I_O = 24$ mA	-	-	0.80	V
		$V_{CC(A)} = 4.5$ V to 5.5 V; $I_O = 100$ μ A	-	-	0.30	V
		$V_{CC(A)} = 4.5$ V; $I_O = 12$ mA	-	-	0.60	V
		$V_{CC(A)} = 4.5$ V; $I_O = 24$ mA	-	-	0.80	V
I_I	input leakage current	$V_I = 5.5$ V or GND	-	-	± 20	μ A
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} [2]				
		$V_{CC(B)} = 3.6$ V; $V_O = V_{CC(B)}$ or GND	-	-	± 20	μ A
		$V_{CC(A)} = 5.5$ V; $V_O = V_{CC(A)}$ or GND	-	-	± 20	μ A
I_{CC}	supply current	$I_O = 0$ A				
		$V_{CC(B)} = 3.6$ V; other inputs at $V_{CC(B)}$ or GND	-	-	40	μ A
		$V_{CC(A)} = 5.5$ V; other inputs at $V_{CC(A)}$ or GND	-	-	40	μ A

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Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
ΔI_{CC}	additional supply current	per pin; $I_O = 0$ A				
		$V_{CC(B)} = 2.7$ V to 3.6 V; $V_I = V_{CC(B)} - 0.6$ V; other inputs at $V_{CC(B)}$ or GND	-	-	5000	μ A
		$V_{CC(A)} = 4.5$ V to 5.5 V; $V_I = V_{CC(A)} - 0.6$ V; other inputs at $V_{CC(A)}$ or GND	-	-	5000	μ A

[1] All typical values are measured at $V_{CC(A)} = 5.0$ V, $V_{CC(B)} = 3.3$ V and $T_{amb} = 25$ °C.

[2] For transceivers, the parameter I_{OZ} includes the input leakage current.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). $V_{CC(A)} = 4.5$ V to 5.5 V; $t_r = t_f \leq 2.5$ ns. For test circuit see Fig. 8.

Symbol	Parameter	Conditions	$V_{CC(B)}$	-40 °C to +85 °C			-40 °C to +125 °C		Unit
				Min	Typ [1]	Max	Min	Max	
t_{PHL}	HIGH to LOW propagation delay	An to Bn; see Fig. 6	2.7 V	1.0	3.6	6.3	1.0	8.0	ns
			3.0 V to 3.6 V	1.0	3.3	6.3	1.0	8.0	ns
		Bn to An; see Fig. 6	2.7 V	1.0	3.4	6.1	1.0	8.0	ns
			3.0 V to 3.6 V	1.0	3.4	6.1	1.0	8.0	ns
t_{PLH}	LOW to HIGH propagation delay	An to Bn; see Fig. 6	2.7 V	1.0	3.3	6.7	1.0	8.5	ns
			3.0 V to 3.6 V	1.0	2.8	6.5	1.0	8.5	ns
		Bn to An; see Fig. 6	2.7 V	1.0	3.0	5.0	1.0	6.5	ns
			3.0 V to 3.6 V	1.0	3.0	5.0	1.0	6.5	ns
t_{PZL}	OFF-state to LOW propagation delay	\overline{OE} to An; see Fig. 7	2.7 V	1.0	4.5	9.0	1.0	11.5	ns
			3.0 V to 3.6 V	1.0	4.5	9.0	1.0	11.5	ns
		\overline{OE} to Bn; see Fig. 7	2.7 V	1.0	4.4	8.7	1.0	11.0	ns
			3.0 V to 3.6 V	1.0	3.8	8.1	1.0	10.5	ns
t_{PZH}	OFF-state to HIGH propagation delay	\overline{OE} to An; see Fig. 7	2.7 V	1.0	4.5	8.1	1.0	10.5	ns
			3.0 V to 3.6 V	1.0	4.5	8.1	1.0	10.5	ns
		\overline{OE} to Bn; see Fig. 7	2.7 V	1.0	4.3	8.7	1.0	11.0	ns
			3.0 V to 3.6 V	1.0	3.2	8.1	1.0	10.5	ns
t_{PLZ}	LOW to OFF-state propagation delay	\overline{OE} to An; see Fig. 7	2.7 V	1.0	2.9	7.0	1.0	9.0	ns
			3.0 V to 3.6 V	1.0	2.9	7.0	1.0	9.0	ns
		\overline{OE} to Bn; see Fig. 7	2.7 V	1.0	3.9	7.7	1.0	10.0	ns
			3.0 V to 3.6 V	1.0	3.5	7.7	1.0	10.0	ns
t_{PHZ}	HIGH to OFF-state propagation delay	\overline{OE} to An; see Fig. 7	2.7 V	1.0	2.8	5.8	1.0	7.5	ns
			3.0 V to 3.6 V	1.0	2.8	5.8	1.0	7.5	ns
		\overline{OE} to Bn; see Fig. 7	2.7 V	1.0	3.3	7.8	1.0	10.0	ns
			3.0 V to 3.6 V	1.0	2.9	7.8	1.0	10.0	ns
$t_{sk(o)}$	output skew time		[2]	-	-	1.0	-	1.5	ns

Symbol	Parameter	Conditions	$V_{CC(B)}$	-40 °C to +85 °C			-40 °C to +125 °C		Unit
				Min	Typ [1]	Max	Min	Max	
C_{PD}	power dissipation capacitance	5 V bus: Bn to An; $V_I = \text{GND to } V_{CC(A)}$; $V_{CC(A)} = 5.0 \text{ V}$	[3]						
		outputs enabled	-	-	17	-	-	-	pF
		outputs disabled	-	-	5	-	-	-	pF
		3 V bus: An to Bn; $V_I = \text{GND to } V_{CC(B)}$; $V_{CC(B)} = 3.3 \text{ V}$	[3]						
		outputs enabled	-	-	17	-	-	-	pF
		outputs disabled	-	-	5	-	-	-	pF

[1] Typical values are measured at $T_{amb} = 25 \text{ °C}$, $V_{CC(A)} = 5.0 \text{ V}$, and $V_{CC(B)} = 2.7 \text{ V}$ and 3.3 V respectively.

[2] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz; f_o = output frequency in MHz

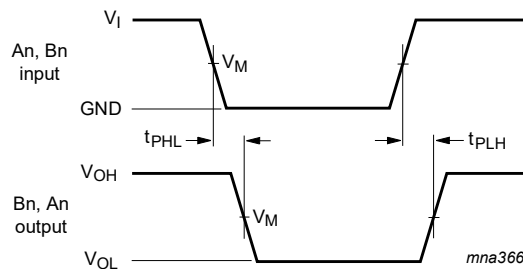
C_L = output load capacitance in pF

V_{CC} = supply voltage in Volts

N = number of inputs switching

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs

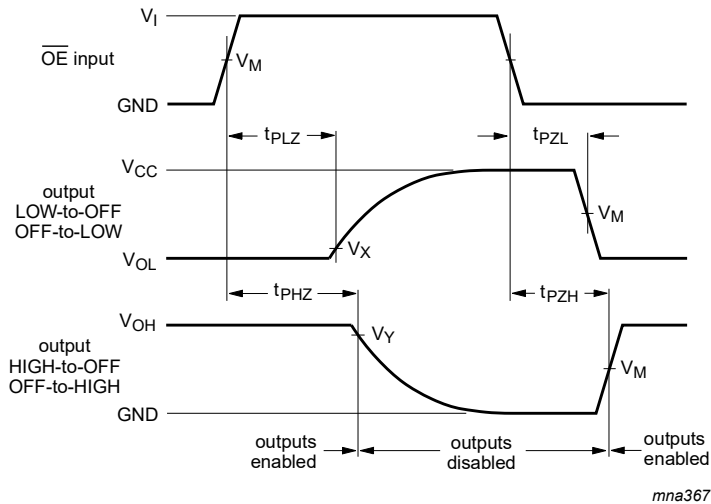
10.1. Waveforms and test circuit



Measurement point are given in [Table 8](#).

V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig. 6. Input (An, Bn) to output (Bn, An) propagation delays



Measurement point are given in [Table 8](#).

V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

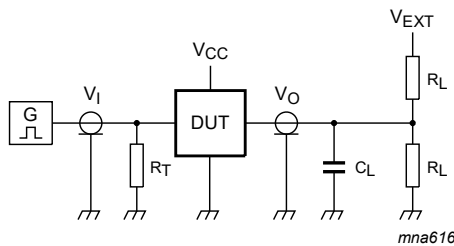
Fig. 7. 3-state enable and disable times

Table 8. Measurement points

Supply voltage		Input		Output		
$V_{CC(A)}$	$V_{CC(B)}$	V_M [1]	V_I [1]	V_M [2]	V_X	V_Y
≤ 2.7 V	≤ 2.7 V	$0.5 V_{CCI}$	V_{CCI}	$0.5 V_{CCO}$	-	-
-	2.7 V to 3.6 V	1.5 V	2.7 V	1.5 V	-	-
≥ 4.5 V	-	$0.5 V_{CCI}$	3.0 V	$0.5 V_{CCO}$	-	-
-	≥ 2.7 V	-	V_{CCI}	-	$V_{OL} + 0.3$ V	$V_{OH} - 0.3$ V

[1] V_{CCI} is the supply voltage associated with the data input port.

[2] V_{CCO} is the supply voltage associated with the data output port.



Test data is given in [Table 9](#). Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

Fig. 8. Test circuit for measuring switching times

Table 9. Test data

Supply voltage		Input	Load		V_{EXT}		
$V_{CC(A)}$	$V_{CC(B)}$	V_I [1]	C_L	R_L	t_{PLH}, t_{PHL}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ} [2]
< 2.7 V	< 2.7 V	V_{CCI}	50 pF	500 Ω	open	GND	$2 \times V_{CCO}$
-	2.7 V to 3.6 V	2.7 V	50 pF	500 Ω	open	GND	$2 \times V_{CCO}$
4.5 V to 5.5 V	-	3.0 V	50 pF	500 Ω	open	GND	$2 \times V_{CCO}$

[1] V_{CCI} is the supply voltage associated with the data input port.

[2] V_{CCO} is the supply voltage associated with the output port.

11. Package outline

SO24: plastic small outline package; 24 leads; body width 7.5 mmSOT137-1

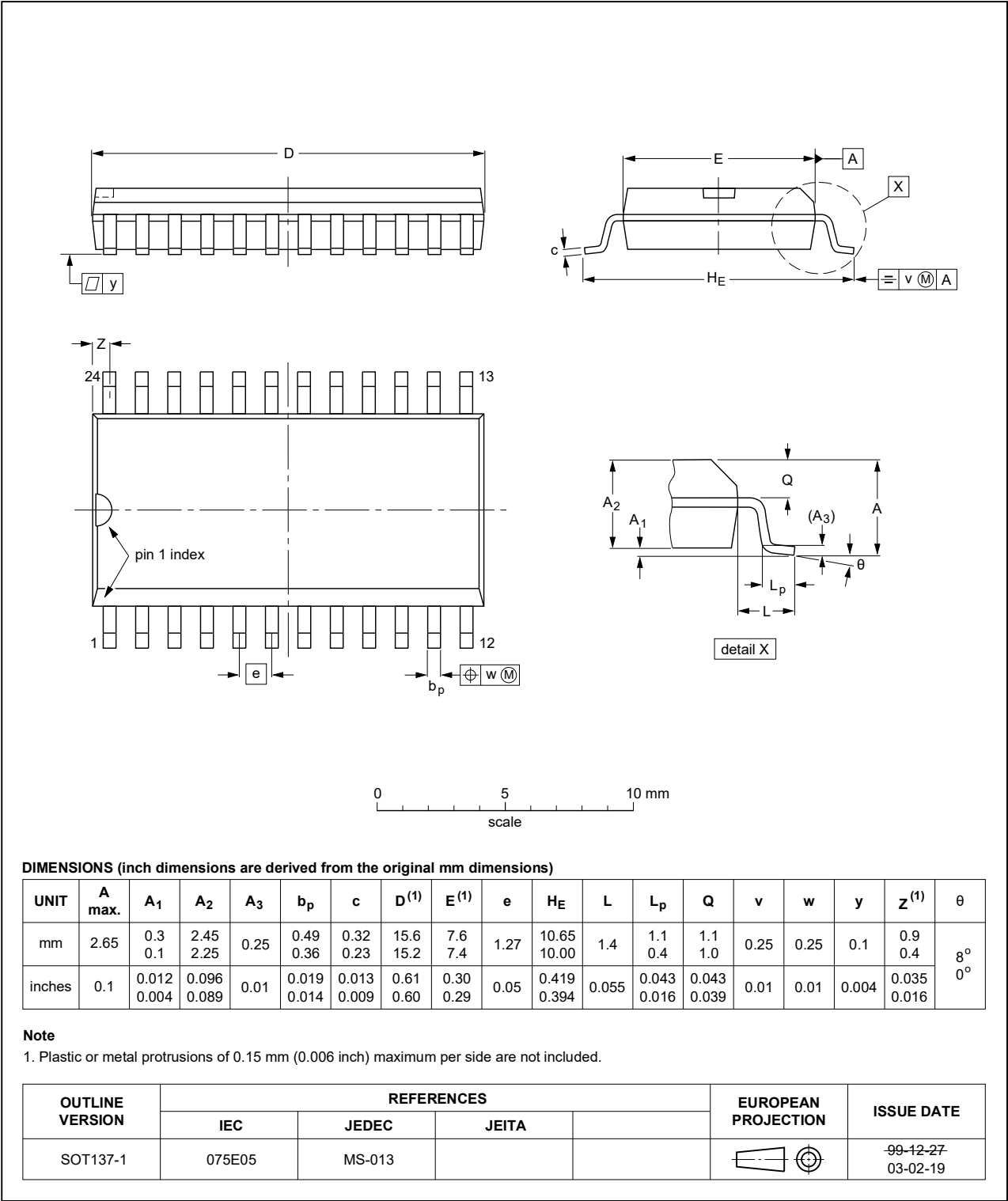


Fig. 9. Package outline SOT137-1 (SO24)

TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm

SOT355-1

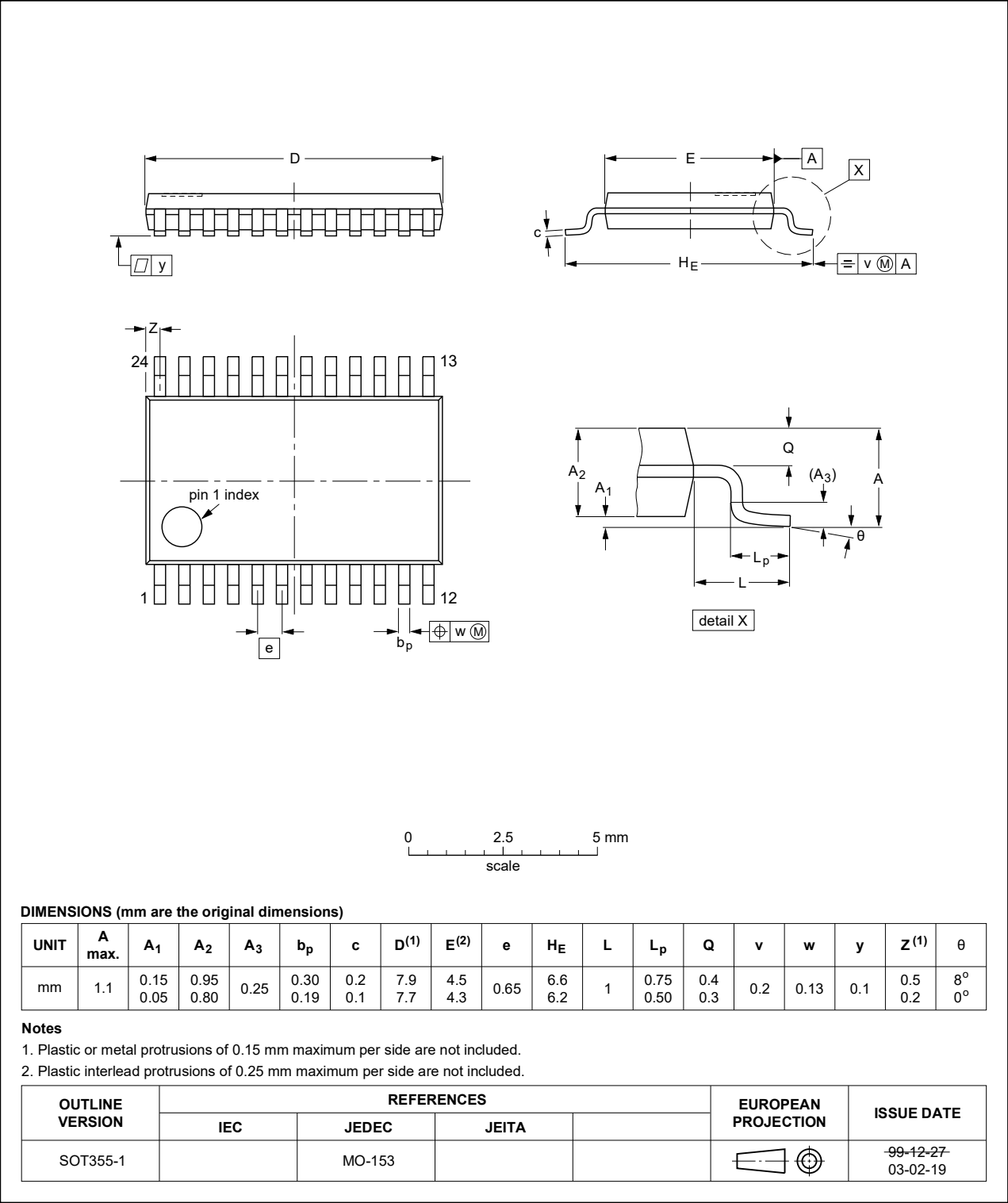


Fig. 10. Package outline SOT355-1 (TSSOP24)

DHVQFN24: plastic dual in-line compatible thermal enhanced very thin quad flat package;
no leads; 24 terminals; body 3.5 x 5.5 x 0.85 mm

SOT815-1

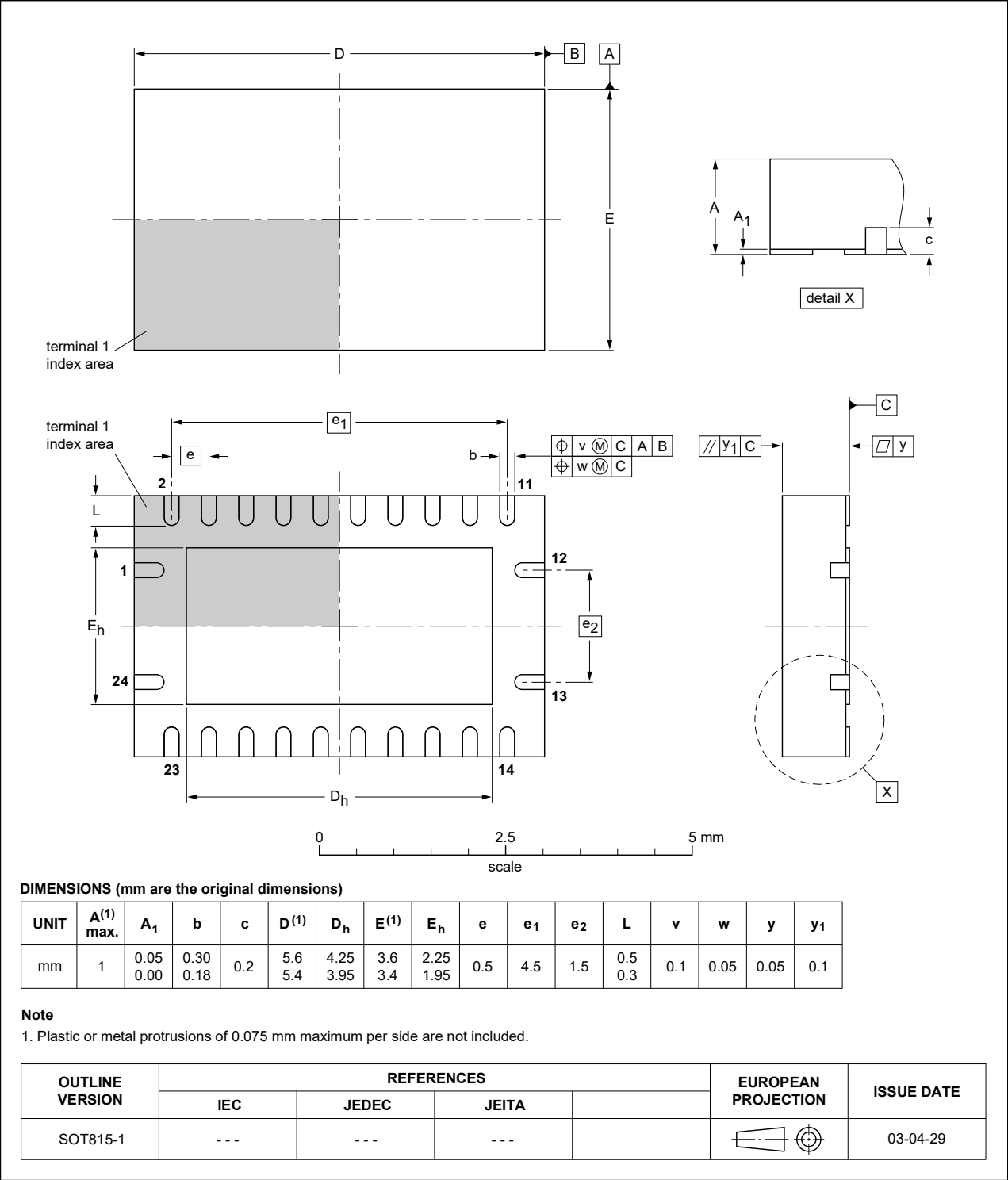


Fig. 11. Package outline SOT815-1 (DHVQFN24)

12. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC4245A v.13	20210827	Product data sheet	-	74LVC4245A v.12
Modifications:	<ul style="list-style-type: none"> Type number 74LVC4245ADB (SOT340-1/SSOP24) removed. 			
74LVC4245A v.12	20210412	Product data sheet	-	74LVC4245A v.11
Modifications:	<ul style="list-style-type: none"> Section 9: ΔI_{CC} conditions have changed. 			
74LVC4245A v.11	20200922	Product data sheet	-	74LVC4245A v.10
Modifications:	<ul style="list-style-type: none"> The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Section 1 updated. Table 4: Derating values for P_{tot} total power dissipation updated. Measurement points related to Fig. 6 and Fig. 7 are given in Table 8. 			
74LVC4245A v.10	20121218	Product data sheet	-	74LVC4245A v.9
Modifications:	<ul style="list-style-type: none"> $V_{CC(A)}$ and $V_{CC(B)}$ changed into $V_{CC(A)}$ and $V_{CC(B)}$ (errata) 			
74LVC4245A v.9	20121120	Product data sheet	-	74LVC4245A v.8
Modifications:	<ul style="list-style-type: none"> Fig. 4: Pin configuration drawing corrected for DHVQFN24 package 			
74LVC4245A v.8	20111122	Product data sheet	-	74LVC4245A v.7
74LVC4245A v.7	20110812	Product data sheet	-	74LVC4245A v.6
74LVC4245A v.6	20080118	Product data sheet	-	74LVC4245A v.5
74LVC4245A v.5	20040330	Product specification	-	74LVC4245A v.4
74LVC4245A v.4	20040211	Product specification	-	74LVC4245A v.3
74LVC4245A v.3	19990615	Product specification	-	74LVC4245A v.2
74LVC4245A v.2	19980729	Product specification	-	74LVC4245A v.1
74LVC4245A v.1	19980729	Product specification	-	-

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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